

ST901T

HIGH VOLTAGE IGNITION COIL DRIVER NPN POWER TRANSISTOR

- n HIGH VOLTAGE SPECIAL DARLINGTON STRUCTURE
- n VERY RUGGED BIPOLAR TECHNOLOGY
- HIGH OPERATION JUNCTION TEMPERATURE
- n HIGH DC CURRENT GAIN

APPLICATIONS

HIGH RUGGEDNESS ELECTRONIC IGNITION FOR SMALL ENGINES

DESCRIPTION

The ST901T is a High Voltage NPN silicon transistor in monolithic special Darlington configuration mounted in Jedec TO-220 plastic package, designed for applications such us electronic ignition for small engines (scooters, lawnmovers, chainsaws).

Figure 1: Package

TO-220

Figure 2: Internal Schematic Diagram

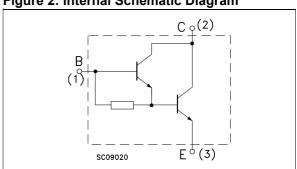


Table 1: Order Codes

Part Number	Marking	Package	Packaging	
ST901T	901T	TO-220	TUBE	

Table 2: Absolute Maximum Ratings

Symbol	Parameter	Value	Unit
V_{CES}	Collector-Emitter Voltage (V _{BE} = 0)	500	V
V_{CEO}	Collector-Emitter Voltage (I _B = 0)	350	V
V_{EBO}	Emitter-Base Voltage (I _C = 0)	5	V
I _C	Collector Current	4	А
I _{CM}	Collector Peak Current (t _p < 5ms)	8	Α
I _B	Base Current	0.5	Α
I _{BM}	Base Peak Current (t _p < 5ms)	2.5	А
P _{tot}	Total Dissipation at T _C = 25 °C	100	W
T _{stg}	Storage Temperature	-65 to 150	°C
TJ	Max. Operating Junction Temperature	150	°C

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Table 3: Thermal Data

R _{thj-case}	Thermal Resistance Junction-Case	Max	1.25	°C/W	
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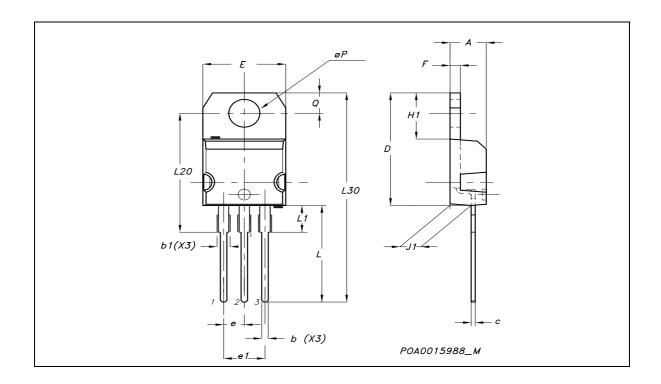
Table 4: Electrical Characteristics (T_{case} = 25 °C unless otherwise specified)

Symbol	Parameter	Test Conditions		Min.	Тур.	Max.	Unit
I _{CES}	Collector Cut-off Current	V _{CE} = 500 V				100	μ A
	(I _E = 0)	V _{CE} = 500 V	T _{case} = 125 °C			500	μ A
I _{CEO}	Collector Cut-off Current	V _{CE} = 350 V				100	μ A
	(I _B = 0)	V _{CE} = 350 V	T _{case} = 125 °C			500	μ A
I _{EBO}	Emitter Cut-off Current	V _{EB} = 5 V				10	μ A
	$(I_C = 0)$						
V _{CEO(sus)} *	Collector-Emitter Sustaining Voltage	I _C = 10 mA	L = 10 mH	350			V
	(I _B = 0)						
V _{CE(sat)} *	Collector-Emitter Saturation Voltage	I _C = 2 A	I _B = 20 mA			2	V
V _{BE(sat)} *	Base-Emitter Saturation Voltage	I _C = 2 A	I _B = 20 mA			1.8	V
h _{FE}	DC Current Gain	I _C = 2 A	V _{CE} = 2 V	1500			
		I _C = 4 A	$V_{CE} = 2 V$	500			
	Functional Test	V _{CC} = 24 V	V _{clamp} = 350 V	4			
		L = 4 mH					
	INDUCTIVE LOAD	V _{CC} = 12 V	V _{clamp} = 250 V				
t _s	Storage Time	L = 4 mH	$I_C = 2 A$		15		μ s
t _f	Fall Time	$I_B = 20 \text{ mA}$	$V_{BE} = -3 V$		1.5		μ s

^{*} Pulsed: Pulsed duration = 300 μ s, duty cycle \leq 1.5 %.

TO-220 MECHANICAL DATA

DIM.		mm.					
DIW.	MIN.	TYP	MAX.	MIN.	TYP.	MAX.	
Α	4.40		4.60	0.173		0.181	
b	0.61		0.88	0.024		0.034	
b1	1.15		1.70	0.045		0.066	
С	0.49		0.70	0.019		0.027	
D	15.25		15.75	0.60		0.620	
Е	10		10.40	0.393		0.409	
е	2.40		2.70	0.094		0.106	
e1	4.95		5.15	0.194		0.202	
F	1.23		1.32	0.048		0.052	
H1	6.20		6.60	0.244		0.256	
J1	2.40		2.72	0.094		0.107	
L	13		14	0.511		0.551	
L1	3.50		3.93	0.137		0.154	
L20		16.40			0.645		
L30		28.90			1.137		
øΡ	3.75		3.85	0.147		0.151	
Q	2.65		2.95	0.104		0.116	



ST901T

Figure 5: Revision History

Version	Release Date	Change Designator
14-Oct-2004	1	First Release.
15-Jan-2005	2	DC current gain range has been modified.

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